



DMT32M5LPS

#### 30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> Tc = +25°С
201/	2.0mΩ @ V <sub>GS</sub> = 10V	150A
30V	3.0mΩ @ V <sub>GS</sub> = 4.5V	100A

## **Description and Applications**

This new generation MOSFET is designed to minimize  $R_{DS(ON)}$  yet maintain superior switching performance. This device is ideal for use in power management and load switch.

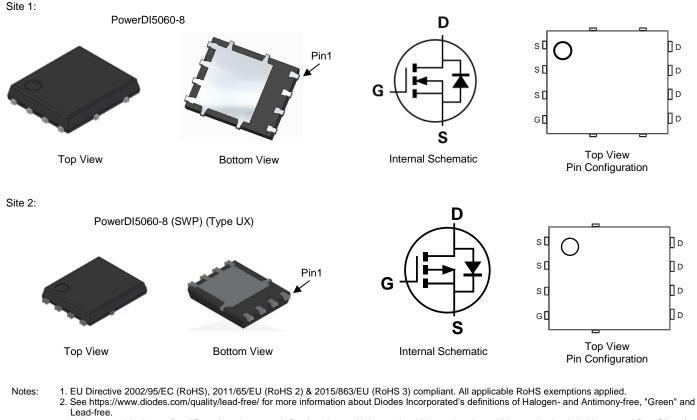
- DC-DC converters
- Load switches

#### Features

- Thermally Efficient Package-Cooler Running Applications
- <1.1mm Package Profile Ideal for Thin Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.097 grams (Approximate)



3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

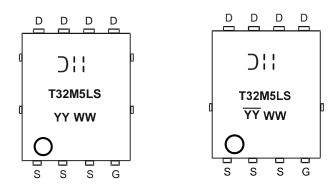


## Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMT32M5LPS-13	PowerDI5060-8	2,500	Tape & Reel	
DMT32M5LPS-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



 $\begin{array}{l} \begin{array}{l} \begin{array}{l} 1\\ 1\end{array} &= \mbox{Manufacturer's Marking} \\ \hline T32M5LS &= \mbox{Product Type Marking Code} \\ \hline \hline YYWW \mbox{or YYWW} &= \mbox{Date Code Marking} \\ \hline \hline YY \mbox{or YY} &= \mbox{Year (ex: 23 = 2023)} \\ \hline WW &= \mbox{Week (01 to 53)} \end{array}$ 



## Maximum Ratings (@T<sub>C</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	30	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	ID	150 120	А		
Maximum Continuous Body Diode Forward Current (Note 6)			ls	80	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Idм	350	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	350	Α
Avalanche Current, L = 0.1mH			las	50	A
Avalanche Energy, L = 0.1mH			E <sub>AS</sub>	140	mJ

## Thermal Characteristics (@Tc = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	3.2	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	54	°C/W
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	PD	100	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@Tc = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	30	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	lgss	—	_	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	1	—	3	V	$V_{DS} = V_{GS}, I_D = 1mA$
Static Drain-Source On-Resistance	Deserve	—	1.6	2.0	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A
Static Drain-Source On-Resistance	RDS(ON)	_	2.3	3.0	11122	$V_{GS} = 4.5V, I_D = 30A$
Diode Forward Voltage	Vsd		0.8	1.1	V	VGS = 0V, IS = 30A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	3944		pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	—	1267	_		
Reverse Transfer Capacitance	Crss	_	186	—		
Gate Resistance	Rg	—	0.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	34	_		V <sub>DS</sub> = 15V, I <sub>D</sub> = 20A
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		68		nC	
Gate-Source Charge	Qgs	_	8	_	nc	
Gate-Drain Charge	Qgd	_	15	_		
Turn-On Delay Time	td(on)		7.2			$V_{DD} = 15V, V_{GS} = 10V,$ $I_D = 15A, R_G = 3\Omega$
Turn-On Rise Time	t <sub>R</sub>	_	13.2	_	ns	
Turn-Off Delay Time	tD(OFF)	_	37.5	—		
Turn-Off Fall Time	tF	_	23.9			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	28.7		ns	
Body Diode Reverse Recovery Charge	Qrr	_	45.8	_	nC	Is = 15A, di/dt = 500A/µs

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

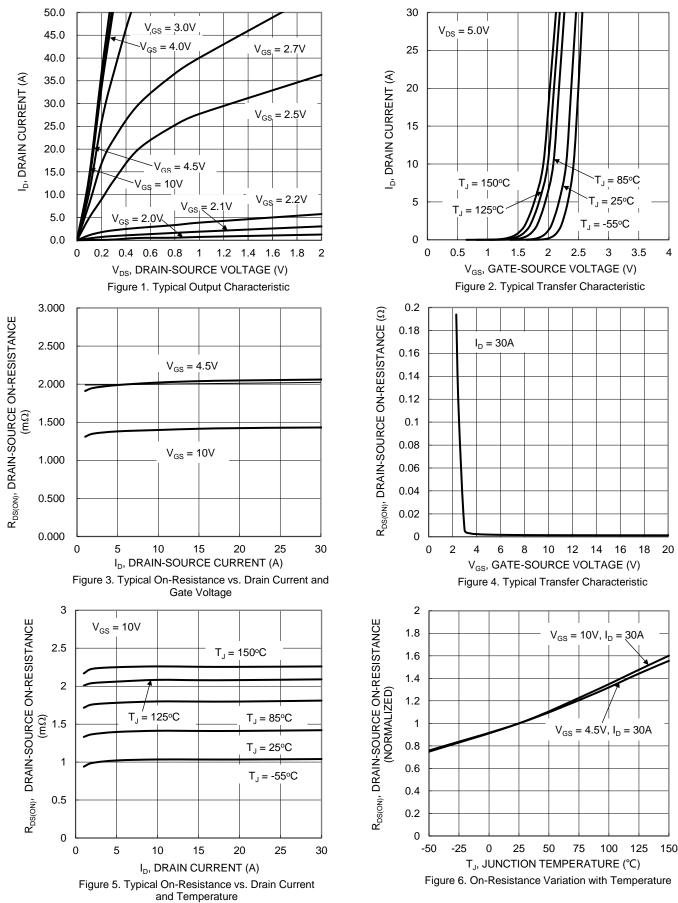
6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

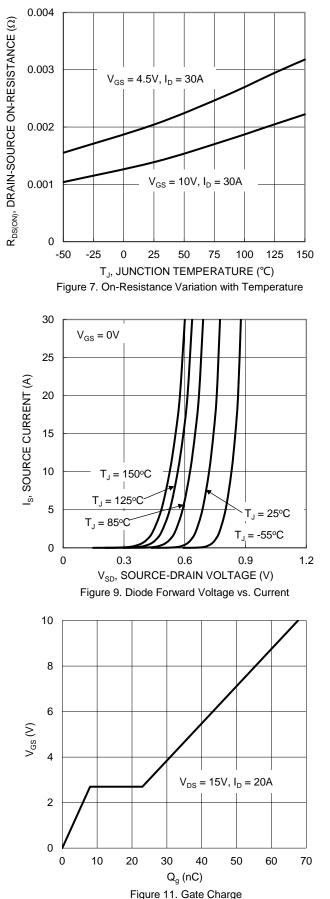


# DMT32M5LPS





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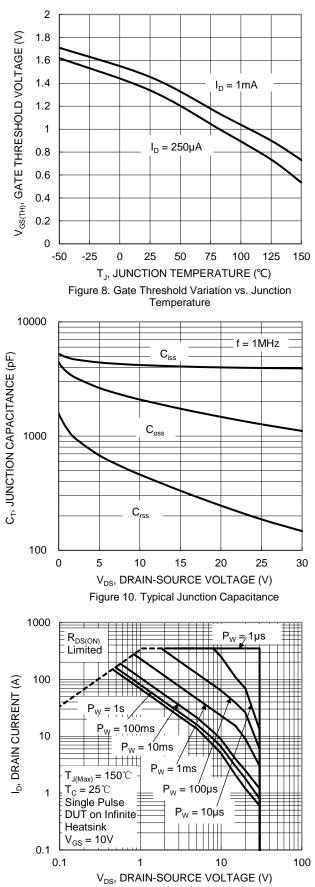
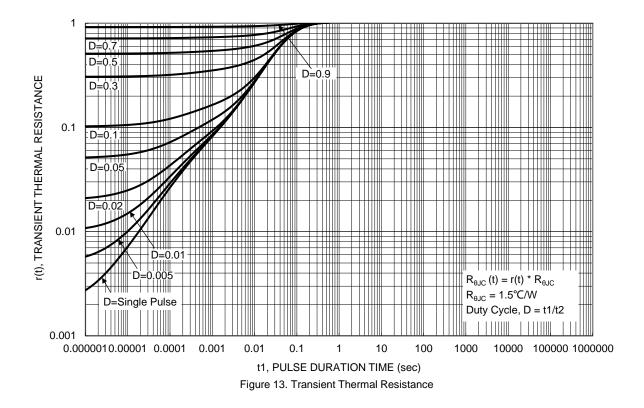


Figure 12. SOA, Safe Operation Area

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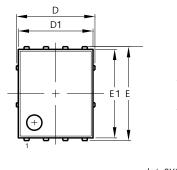




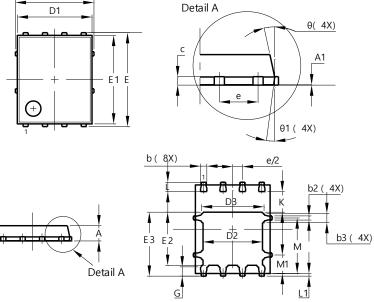
# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

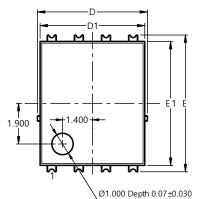


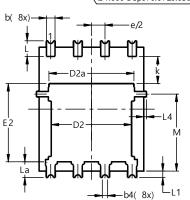


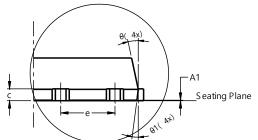


	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E		6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC			
G	0.51	0.71	0.61		
ĸ	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
AI	Dimens	ions in n	nm		

Site 2:

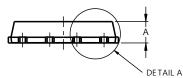






PowerDI5060-8 (SWP) (Type UX)

DETAIL A



PowerDI5060-8 (SWP)					
	(Type UX)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	-		
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	(	).25REF			
С	0.230	0.330	0.277		
D	5	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	6	.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a		4.595	4.395		
е	1	.27BSC	)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a		.050RE			
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

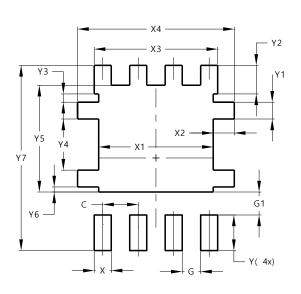
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## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### Site 1:

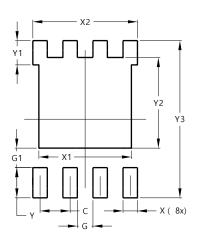


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

#### PowerDI5060-8 (SWP) (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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